SCHIVE INFORMATION

CATV Amplifier Module

Features

- Specified for 77- and 110-Channel Loading
- Excellent Distortion Performance
- · Silicon Bipolar Transistor Technology
- Unconditionally Stable Under All Load Conditions

Applications

- CATV Systems Operating in the 40 to 750 MHz Frequency Range
- Input Stage Amplifier in Optical Nodes, Line Extenders and Trunk Distribution Amplifiers for CATV Systems
- Driver Amplifier in Linear General Purpose Applications
- Output Stage Amplifier on Applications Requiring Low Power Dissipation

Description

- 24 Vdc Supply, 40 to 750 MHz, CATV Forward Amplifier Module
- Replaced MHW7222B. There are no form, fit or function changes with this part replacement.
- RoHS Compliant

MHW7222BN

750 MHz 22.7 dB GAIN 110-CHANNEL CATV AMPLIFIER MODULE

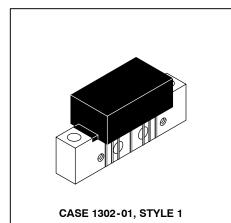


Table 1. Maximum Ratings

| Rating | Symbol | Value | Unit |
|----------------------------------|------------------|--------------|------|
| DC Supply Voltage | V _{CC} | +28 | Vdc |
| RF Input Voltage (Single Tone) | V _{in} | +70 | dBmV |
| Operating Case Temperature Range | T _C | - 20 to +100 | °C |
| Storage Temperature Range | T _{stg} | - 40 to +100 | °C |

Table 2. Electrical Characteristics ($V_{CC} = 24 \text{ Vdc}$, $T_C = +30^{\circ}\text{C}$, 75 Ω system unless otherwise noted)

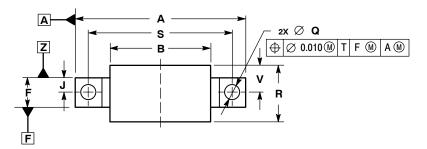
| Characteristic | | Symbol | Min | Тур | Max | Unit |
|---|---------------------------|---|--------------|--------------|--------------|--------|
| Frequency Range | | BW | 40 | _ | 750 | MHz |
| Power Gain | f = 50 MHz f = 750 MHz | G _p | 21.4 22.2 | 21.9 22.7 | 22.4 23.2 | dB |
| Slope (f = 40 - 750 MHz) | | S | 0.2 | 0.7 | 1.2 | = |
| Gain Flatness (Peak To Valley) | (f = 40 - 750 MHz) | G _F | _ | 0.4 | 0.6 | = |
| Input/Output Return Loss @ f = 40 MHz | | IRL/ORL | 20 | 25 | _ | dB |
| Derate Return Loss @ f > 40 MHz | | RLD | _ | _ | 0.006 | dB/MHz |
| Composite Second Order (V _{out} = +40 dBmV/ch; 110 Channels) (V _{out} = +44 dBmV/ch; 77 Channels) | | CSO ₁₁₀ CSO ₇₇ | _ | - 67 - 67 | - 60 - 60 | dBc |

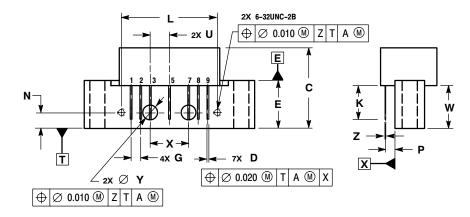
Table 2. Electrical Characteristics (V_{CC} = 24 Vdc, T_{C} = +30°C, 75 Ω system unless otherwise noted) (continued)

| Characteristic | | Min | Тур | Max | Unit |
|--|-----------------|----------|--------------|--------------|------|
| Cross Modulation Distortion (V _{out} = +40 dBmV/ch, 110-Channel @ Fm = 55.25 MHz) (V _{out} = +44 dBmV/ch, 77-Channel @ Fm = 55.25 MHz) | | <u> </u> | - 63 - 59 | - 60 - 56 | dBc |
| Composite Triple Beat (V _{out} = +40 dBmV/ch, 110-Channels, Worst Case) (V _{out} = +44 dBmV/ch, 77-Channels, Worst Case) | | _ | - 64 - 65 | - 61 - 62 | dBc |
| Noise Figure f = 50 MHz f = 750 MHz | NF | _ _ | 3.7 5 | 4.5 6.5 | dB |
| DC Current | I _{DC} | 180 | 220 | 240 | mA |

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PACKAGE DIMENSIONS





- NOTES:
 1. DIMENSIONS ARE IN INCHES.
 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

| | INCHES | | MILLIMETERS | | |
|-----|-----------|-----------|-------------|--------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | | 1.775 | | 45.085 | |
| В | | 1.085 | | 27.559 | |
| C | | 0.840 | | 21.336 | |
| D | 0.015 | 0.021 | 0.381 | 0.533 | |
| Е | 0.465 | 0.510 | 11.811 | 12.954 | |
| F | 0.300 | 0.325 | 7.62 | 8.255 | |
| G | 0.100 | BSC | 2.540 | BSC | |
| J | 0.156 | BSC | 3.962 | 2 BSC | |
| K | 0.315 | 0.355 | 8.001 | 9.017 | |
| L | 1.000 BSC | | 25.400 BSC | | |
| N | 0.165 BSC | | 4.191 BSC | | |
| P | 0.100 BSC | | 2.540 BSC | | |
| Q | 0.148 | 0.168 | 3.759 | 4.267 | |
| R | | 0.600 | | 15.24 | |
| S | 1.500 BSC | | 38.100 BSC | | |
| U | 0.200 | BSC | 5.080 | BSC | |
| ٧ | | 0.250 | | 6.350 | |
| W | 0.435 | | 11.049 | | |
| Х | 0.400 | 0.400 BSC | | 0 BSC | |
| Υ | 0.152 | 0.163 | 3.861 | 4.140 | |
| Z | 0.009 | 0.011 | 0.229 | 0.279 | |

- STYLE 1:
 PIN 1. RF INPUT
 2. GROUND
 3. GROUND
 4. DELETED
 5. VDC
 6. DELETED
 7. GROUND
 8. GROUND
 9. RF OUTPUT

CASE 1302-01 ISSUE E

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